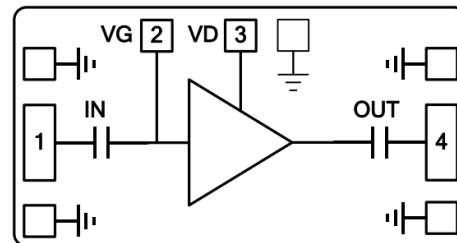


Features

- Two Working Modes: High power consumption
Low power consumption
- Frequency: 6-18GHz
- Gain: 21 dB @ 53 mA; 20 dB @ 33 mA
- Noise Figure: 1.3 dB
- P1dB: +16 dBm @ 53 mA; +13 dBm @ 33 mA
- Self Biasing: +5 V @ 53 mA VG is suspended
+5 V @ 33 mA VG is grounded
- Input/Output: 50Ω
- Die Size: 1.5 x 0.8 x 0.1 mm

Functional Block Diagram

Typical Applications

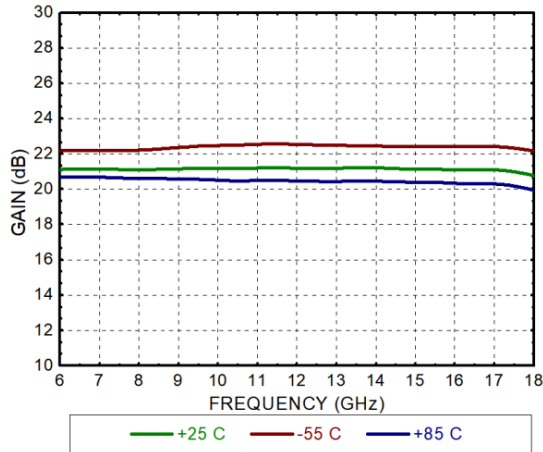
- Test Instrumentation
- Microwave Radio & VSAT
- Military & Space
- Telecom Infrastructure
- Fiber Optics

Electrical Specifications
TA = +25°C, VDD = +5V, IDD = 53mA

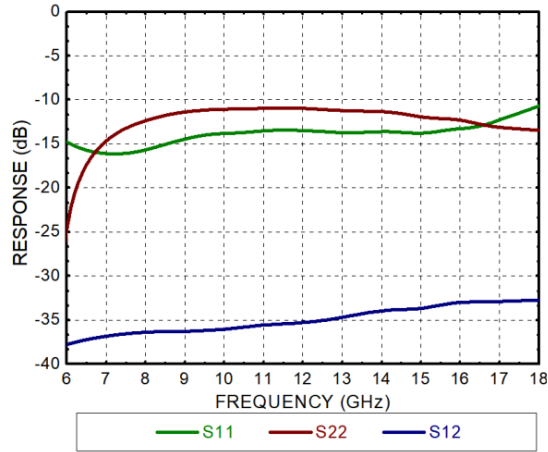
Parameters	VG is suspended			VG is grounded			Units
	Min.	Typ.	Max.	Min.	Typ.	Max.	
Frequency	6-18			6-18			GHz
Gain		21			20		dB
Gain Flatness		±0.2			±0.5		dB
Noise Figure		1.3			1.3		dB
Output 1dB Compression (P1dB)		16			13.5		dBm
Saturated Output Power (P_{sat})		17.5			15		dBm
Output IP3		28			25		dBm
Input Return Loss		12			12		dB
Output Return Loss		12			12		dB
Operating current	30	53	75	20	33	50	mA



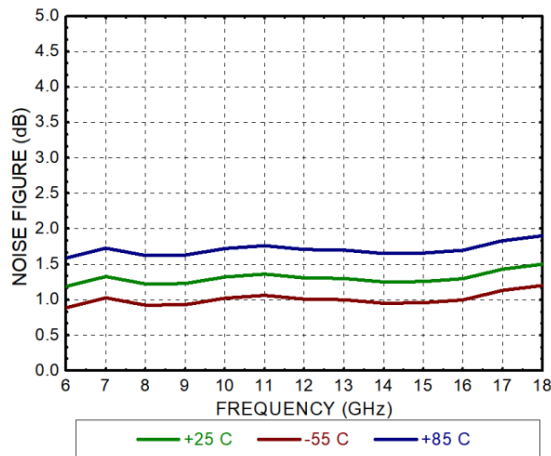
Gain @ VG Suspended



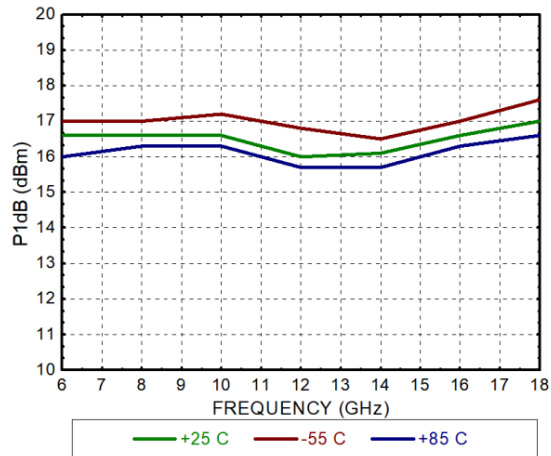
Return Loss & Reverse Isolation @ VG Suspended



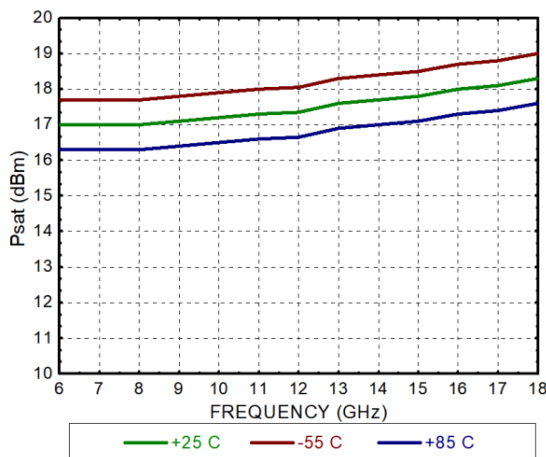
Noise Figure @ VG Suspended



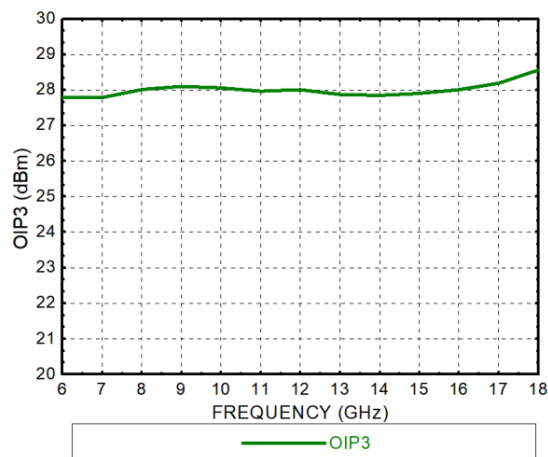
Output Power P₁ @ VG Suspended



Psat @ VG Suspended

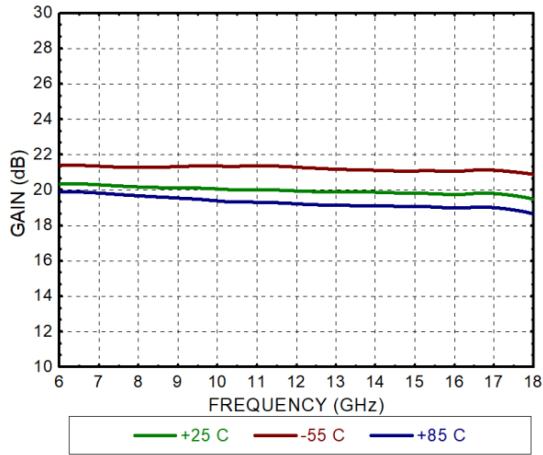


OIP3 @ VG Suspended

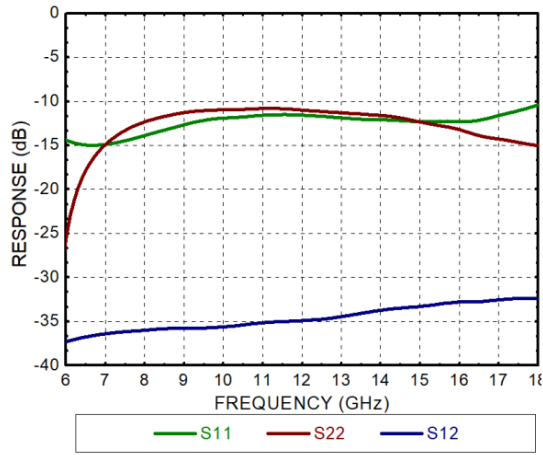




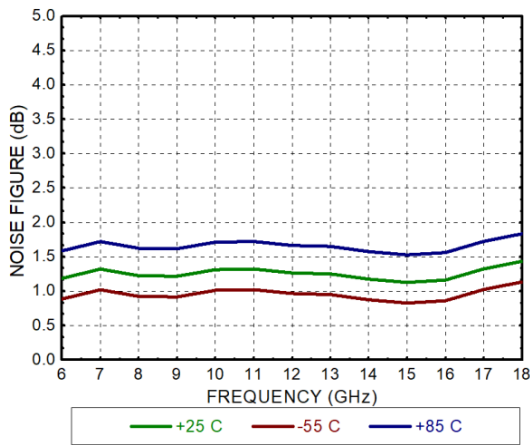
Gain @ VG Grounded



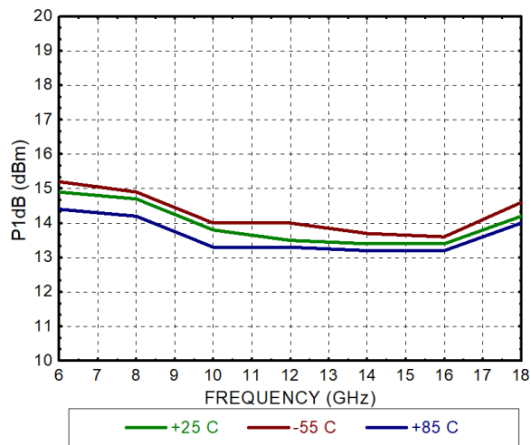
Return Loss & Reverse Isolation @ VG Grounded



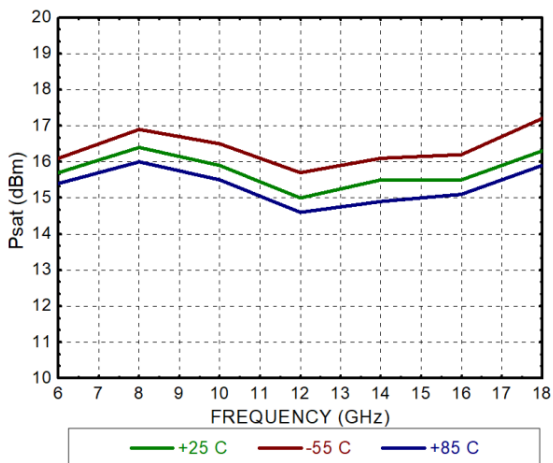
Noise Figure @ VG Grounded



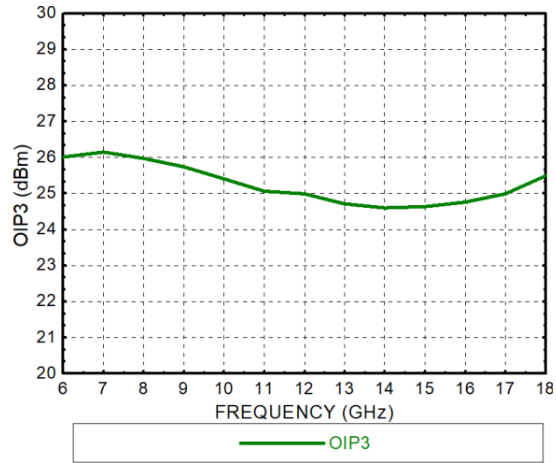
Output Power P₁ @ VG Grounded



Psat @ VG Grounded

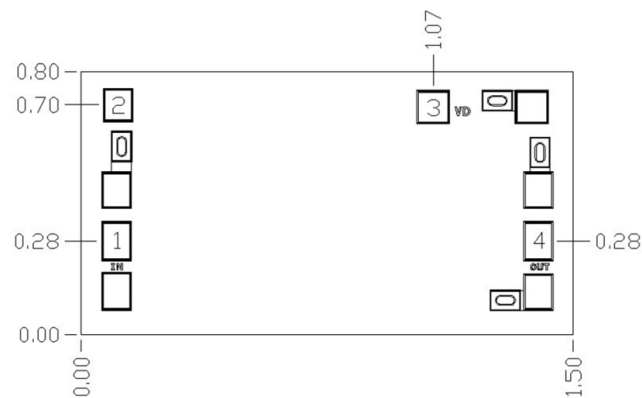


OIP3 @ VG Grounded





Outline Drawing:
All Dimensions in mm



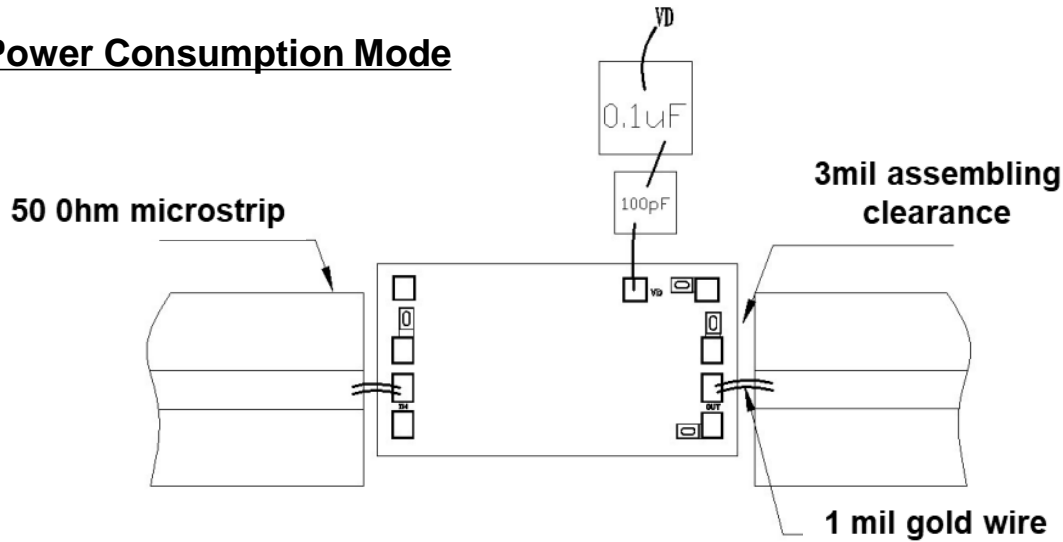
Pad Description

Pad	Function	Description
1	IN	This pad is AC coupling, 50 ohm matched
2	VG	This pad can adjust working mode; Work in high power mode when VG is suspended , work in low power mode when VG is grounded
3	VD	This pad provides the power supply voltage of the amplifier and needs to be externally connected with the 100pF bypass capacitor.
4	OUT	This pad is AC coupling, 50 ohm matched
Die bottom	GND	Die bottom must be connected to RF/DC ground.

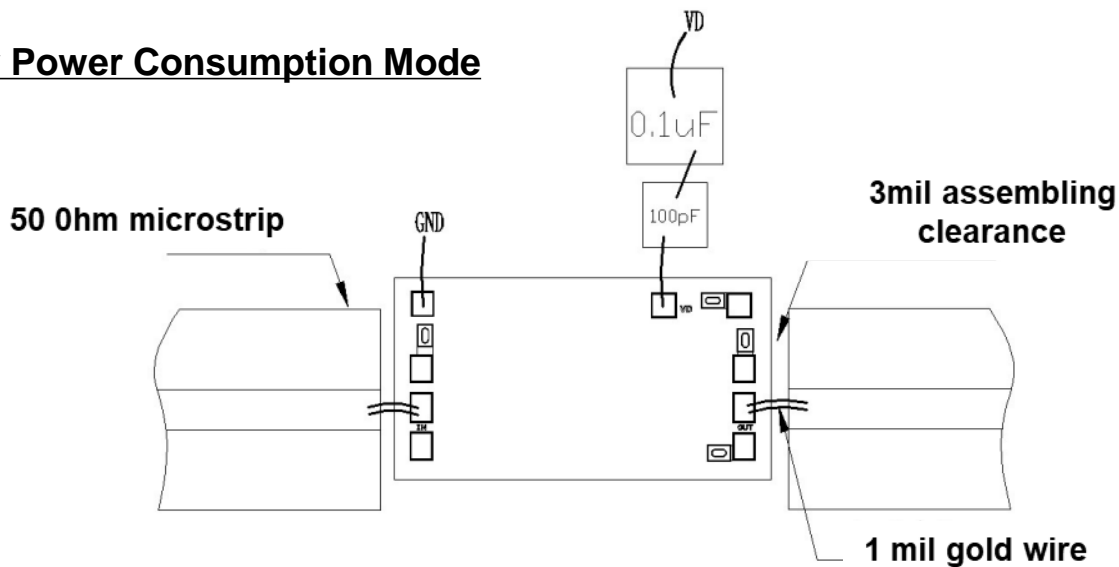


Assembly Drawing

High Power Consumption Mode



Low Power Consumption Mode



Notes:

1. Die thickness: 100 μ m
2. Typical bond pad is 100*100 μ m²
3. Bond pad metalization: Gold
4. Backside metalization: Gold
5. Backside of the die (GND)
6. No connection required for unlabeled bond pads

Maximum Ratings:

1. Power supply voltage (VD): +6V
2. RF input power: +18dBm
3. Storage temperature: -65°C to +150°C
4. Operating temperature: -55°C to +85°C